



# Specification for a Sinewave Output Thru-Hole OCXO MtronPTI P/N: XO5085-051R

## **Electrical Specifications:**

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Nominal Frequency	Fo		100.000000		MHz	
		F	requency Stab	oilities		
vs. Temperature	∆F⊤/F	-100		+100	ppb	Over the Operating Temperature Range
Daily Aging		-5		+5	ppb	
1 Year Aging		-0.5		+0.5	ppm	After 30-days Power On
20-Years Aging		-2		+2	ppm	
			RF Output	t		
Output Type			Sinewave			
Output Level			+12		dBm	
Output Load			50		Ω	±10%
		Fi	requency Adjus	stment		
Adjustment Method			External '	Voltage		
Adjustment Voltage	VTUNE	0		+10	VDC	
Adjustment Range		±1.0			ppm	
Adjustment Slope			Posit	ive		
		Α	dditional Parar	neters		
			-100		dBc/Hz	10Hz Offset
Phase Noise				-135	dBc/Hz	100Hz Offset
(Under Static				-162	dBc/Hz	1kHz Offset
Conditions)				-175	dBc/Hz	10kHz Offset
				-178	dBc/Hz	100kHz Offset
Harmonics				-30	dBc	
Spurious				-75	dBc	
Warm-up Time				5	minutes	To within ±0.1ppm of the frequency after 1-hour of operation @ 25°C
			nal Parameters			
			pply Voltage &			
Operating Temperature	OTR	-20		+75	°C	Full Specification Compliance
Storage Temperature	STR	-55		+85	°C	
Operating Voltage	Vcc	+11.4	+12.0	+12.6	VDC	
Power Consumption			1.2		Watts	Steady state @ 25°C, In Still Air
				4.0	Watts	@ Warm-up

## **Environmental Conditions:**

Seal	Hermetic
RoHS	Full RoHS Compliance



2525 Shader Road Orlando Florida 32804 USA Phone: 407-298-2000 Fax: 407-293-2979 Website: www.mtronpti.com AMEX: LGL



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### Mechanical, Marking and Layout Information:

Part Marking	
Line 1	MtronPTI
Line 2	XO5085-051R
Line 3	100.0000MHz
Line 4	Serial Number
Line 5	Date Code

Legend		
уу	Year	
ww	Work Week	

Pin	Function
1	RF Output
2	Case Ground
3	V <sub>TUNE</sub>
4	NC
5	Supply Voltage

476

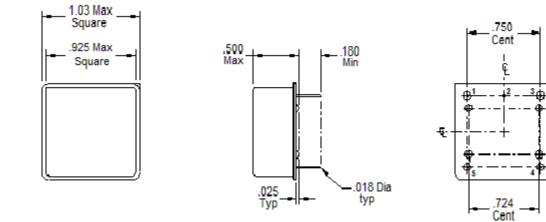
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#### **Data Sheet Revision Table:**

Date	Rev.	Orig.	Details of Revision
03-13-15	А	DPD	Original Draft.